TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXH16373FT

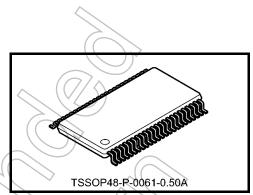
Low-Voltage 16-Bit D-Type Latch with Bushold

The TC74VCXH16373FT is a high-performance CMOS 16-bit D-type latch. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}) which are common to each byte. It can be used as two 8-bit latches or one 16-bit latch. When the \overline{OE} input is high, the outputs are in a high-impedance state.

The D data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25g (typ.)

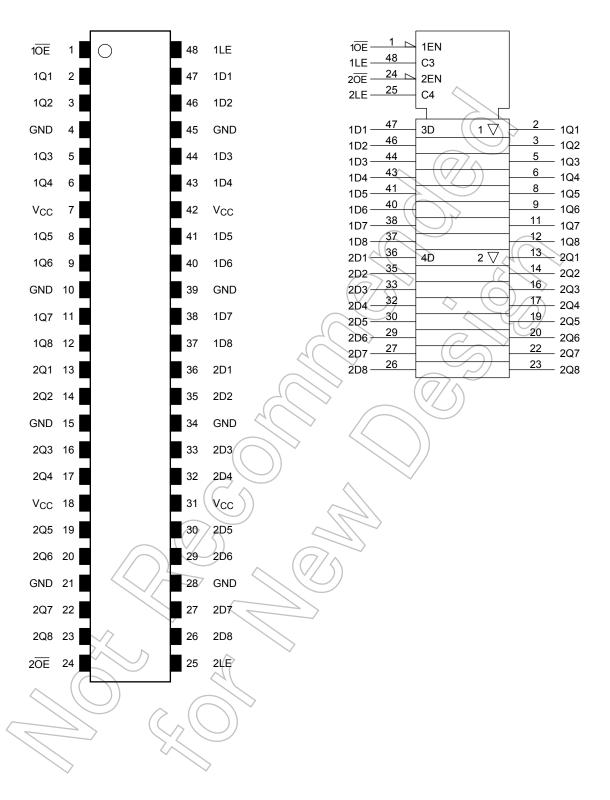
Features

- Low-voltage operation: V_{CC} = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: $t_{pd} = 3.0 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
 - : $t_{pd} = 3.4 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$
 - $: t_{pd} = 5.7 \text{ ns (max) (V}_{CC} = 1.8 \text{ V})$
- Output current: I_{OH}/I_{OL} = ±24 mA (min) (V_{CC} = 3.0 V)
 - $: I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$
 - $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$
- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V
 - Human body model ≥ ±2000 V
- Package: TSSOP
- 3.6-V tolerant function and power-down protection control inputs and outputs



Pin Assignment (top view)

IEC Logic Symbol



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Truth Table

	Outputs		
1 OE	1LE	1D1-1D8	1Q1-1Q8
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

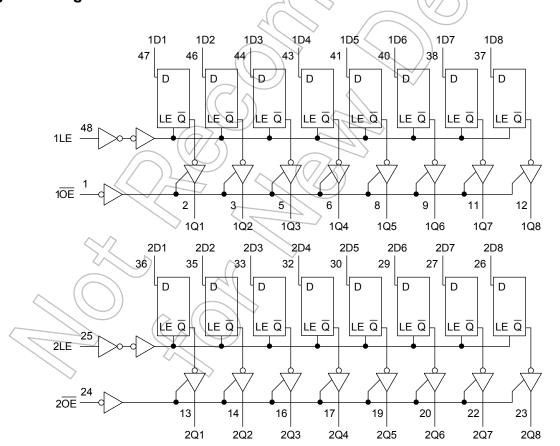
	Outputs		
2OE	2LE	2D1-2D8	2Q1-2Q8
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram



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Absolute Maximum Ratings (Note 1)

Characteris	Characteristics		Symbol Rating	
Power supply voltage		V _{CC}	−0.5 to 4.6	V
DC input voltage	(OE , LE)	Visi	-0.5 to 4.6	V
DC Input voltage	(An)	V _{IN}	-0.5 to V _{CC} + 0.5	V 4
DC output voltage		Vour	-0.5 to 4.6 (Note 2)	V
DC output voltage		V _{OUT}	-0.5 to V _{CC} + 0.5 (Note 3)	
Input diode current		I _{IK}	-50	mA
Output diode current		I _{OK}	±50 (Note 4)	(mA)
Output current	Output current		±50	mA
Power dissipation		P _D	400	mW
DC V _{CC} /ground current per supply pin		I _{CC} /I _{GND}	±100	→ mA
Storage temperature		T _{stg}	-65 to 150	°C <

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc



Operating Ranges (Note 1) (Note 2)

Characteris	Characteristics		Characteristics Symbol		Rating	Unit
Device eventurelle		V _{CC}	1.8 to 3.6	V		
Power supply voltage		VCC	1.2 to 3.6 (Note 3)	V		
Input voltage	(OE , LE)	\/	-0.3 to 3.6	V		
input voitage	(An)	V _{IN}	0 to V _{CC}	V		
Output voltage		\/a	0 to 3.6 (Note 4)	V		
Output voltage		V _{OUT}	0 to V _{CC} (Note 5)	v (
			±24 (Note 6)			
Output current		I _{OH} /I _{OL}	±18 (Note 7)	mA		
			±6 (Note 8)	(\bigcirc)		
Operating temperature		T _{opr}	-40 to 85	,c		
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V		

- Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.
- Note 2: Floating or unused control inputs must be held high or low.
- Note 3: Data retention
- Note 4: OFF state
- Note 5: High or low state
- Note 6: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- Note 7: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
- Note 8: $V_{CC} = 1.8 \text{ V}$
- Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

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Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characteris	stics	Symbol	Test Co	Test Condition		Min	Max	Unit
Input voltage	H-level	V_{IH}	_	-	2.7 to 3.6	2.0	_	V
iliput voltage	L-level	V _{IL}	_	_	2.7 to 3.6	_	8.0	V
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2		
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
				$I_{OL} = 100 \mu\text{A}$	2.7 to 3.6		0.2	
	L-level	Vol	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 12 mA	2.7	*	0.4	
	L-level	VOL	AIN = AIH OL AIT	I _{OL} = 18 mA	3.0	7//	0.4	
				I _{OL} = 24 mA	3.0)	0.55	
Input leakage	(OE , LE)	l	V _{IN} = 0 to 3.6 V		2.7 to 3.6		±5.0	^
current	(An)	I _{IN}	V _{IN} = V _{CC} or GND		2.7 to 3.6	(±5.0	μА
Bushold input minim	num drive	l	V _{IN} = 0.8 V		3.0)	75		^
hold current		lı (HOLD)	V _{IN} = 2.0 V	> (Q)	3.0	-75	_	μА
Bushold input over-o	drive current	1		(Note 1)	3.6	_	450	Δ.
to change state		I _{I (OD)}		(Note 2)	3.6	_	-450	μА
3-state output OFF	state current	l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6	_	±10.0	μΑ
Power-off leakage c	urrent	loff	V _{OUT} = 0 to 3.6 V	\wedge	0	_	10.0	μА
Quiaccent cumple:	urrant		V _{IN} = V _{CC} or GND		2.7 to 3.6	_	20.0	
Quiescent supply current		lcc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	2.7 to 3.6	_	±20.0	μΑ
Increase in I _{CC} per	input	Alcc	$V_{IH} = V_{CC} - 0.6 V$	3)	2.7 to 3.6	_	750	μΑ

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

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Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteris	stics	Symbol	Test Co	Test Condition V _{CC} (V)		Min	Max	Unit
lanut valtana	H-level	V _{IH}	_	_	2.3 to 2.7	1.6	_	V
Input voltage	L-level	V _{IL}	_	_	2.3 to 2.7	_	0.7	V
				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	2.3	2.0	_	
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				$I_{OH} = -18 \text{ mA}$	2.3	1.7	_	V
				I _{OL} = 100 μA	2.3 to 2.7		0.2	
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 12 mA	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	\mathcal{I}	0.6	
Input leakage	(OE , LE)	l.s.	$V_{IN} = 0$ to 3.6 V		2.3 to 2.7	,	±5.0	μА
current	(An)	I _{IN}	$V_{IN} = V_{CC}$ or GND	(7)	2.3 to 2.7	/	>±5.0	μА
Bushold input minim	um drive	l	$V_{IN} = 0.7 V$		2.3	45) —	μА
hold current		I _I (HOLD)	V _{IN} = 1.6 V		2.3	45	_	μА
Bushold input over-o	drive current	li va ev		(Note 1)	2.7		300	^
to change state		I _{I (OD)}		(Note 2)	2.7	_	-300	μА
3-state output OFF	state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7	_	±10.0	μА
Power-off leakage c	urrent	l _{OFF}	V _{OUT} = 0 to 3.6 V		0	_	10.0	μА
Outagaget gunstic su	rrant	1	V _{IN} = V _{CC} or GND		2.3 to 2.7		20.0	^
Quiescent supply cu	ment	Icc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	2.3 to 2.7		±20.0	μΑ

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.

Note 3: Outputs high impedance only.

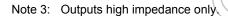


DC Characteristics (Ta = -40 to 85° C, $1.8 \text{ V} \le \text{V}_{\text{CC}} < 2.3 \text{ V})$

Characteris	tics	Symbol	Test Co	ondition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	_	_	1.8 to 2.3	0.7 × V _{CC}		V
input voltage	L-level	V _{IL}	_	_	1.8 to 2.3	_	0.2 × V _{CC}	V
	H-level	VoH	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8	Vcc 0.2		
Output voltage				I _{OH} = -6 mA	7/1,8	1.4	_	V
	L-level	VOI	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8		0.2	
	L-level	VOL	AIN — AIH OI AIL	I _{OL} = 6 mA	1.8	_	0.3	
Input leakage	(OE , LE)	I _{IN}	$V_{IN} = 0$ to 3.6 V		1.8	_	±5.0	μА
current	(An)	IN	$V_{IN} = V_{CC}$ or GND		1.8		±5.0	μΛ
Bushold input minim	um drive	l _{I (HOLD)}	V _{IN} = 0.36 V		1.8	25	/	μА
hold current		ii (HOLD)	V _{IN} = 1.26 V	(O/Λ)	1.8	-25	> _	μιτ
Bushold input over-c	Irive current	I _{I (OD)}		(Note 1)	1.8	(4)	200	μА
to change state		11 (OD)		(Note 2)	1.8		-200	μΑ
3-state output OFF s	state current	loz	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.8	_	±10.0	μА
Power-off leakage co	urrent	loff	V _{OUT} = 0 to 3.6 V	· ((//	0		10.0	μА
Quiogoant aunchi au	rront	laa	V _{IN} = V _{CC} or GND		1.8	_	20.0	^
Quiescent supply cu	Hent	Icc	V _{CC} ≤ V _{OUT} ≤ 3.6 V	(Note 3)	1.8	_	±20.0	μА

Note 1: An external driver must source at least the specified current to switch LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch HIGH-to-LOW.





AC Characteristics (Ta = –40 to 85°C, input: $t_r = t_f$ = 2.0 ns, C_L = 30 pF, R_L = 500 Ω) (Note 1)

Characteristics	Symbol	Test Condition		Min	Max	Unit
			V _{CC} (V)			
Propagation delay time	t_{pLH}		1.8	1.5	5.7	
(D-Q)	t _{pHL}	Figure 1, Figure 2	2.5 ± 0.2	1.0	3.4	ns
(2 4)	SPITE		3.3 ± 0.3	0.8	3.0	
Dranagation delay time	4		1.8	1.5	6.0	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	1.0	3.9	ns
(LE-Q)	t _{pHL}	~ ((3.3 ± 0.3	0.8	3.0	
	t		1.8	1.5	7.0	
3-state output enable time	t _{pZL}	Figure 1, Figure 3	2.5 ± 0.2	1.0	4.6	ns
	^t pZH		3.3 ± 0.3	0.8	3.5	
		4(>)	1.8	1,5	5.0	ns
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	2.5 ± 0.2	1.0	3.8	
		(\bigcirc/\bigcirc)	3.3 ± 0.3	0.8	3.5	
NA:i			1.8	3.0) —	ns
Minimum pulse width	t _{w (H)}	Figure 1, Figure 2	2.5 ± 0.2	1.5	_	
(LE)		4(>)	3.3 ± 0.3	1.5	_	
			1.8	2.5	_	
Minimum set-up time	ts	Figure 1, Figure 2	2.5 ± 0.2	1.5	_	ns
		4()	3.3 ± 0.3	1.5	_	
			1.8	1.0	_	
Minimum hold time	th	Figure 1, Figure 2	2.5 ± 0.2	1.0	_	ns
			3.3 ± 0.3	1.0	_	
	. ((1.8	_	0.5	
Output to output skew	tosLH	(Note 2)	2.5 ± 0.2	_	0.5	ns
	tosHL		3.3 ± 0.3	_	0.5	

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Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition			Тур.	Unit
	,			V _{CC} (V)	71	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	0.25	
Quiet output maximum dynamic V _{OL}	V_{OLP}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	8.0	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	-0.25	
Quiet output minimum dynamic V _{OI}	V_{OLV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	-0.6	V
, 01		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	-0.8	
		V _{IH} = 1.8 V, V _{IL} = 0 V	(Note)	1.8	1.5	
Quiet output minimum dynamic V _{OH}	V _{OHV}	V _{IH} = 2.5 V, V _{IL} = 0 V	(Note)	2.5	1.9	V
		V _{IH} = 3.3 V, V _{IL} = 0 V	(Note)	3.3	2.2	

Note: Parameter guaranteed by design.

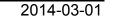
Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	(0)	Vcc (V)	Тур.	Unit
Input capacitance	C _{IN}			1.8, 2.5, 3.3	6	pF
Output capacitance	CO		//5)	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

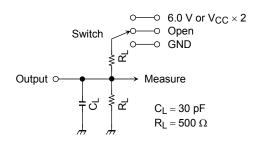
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$



AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

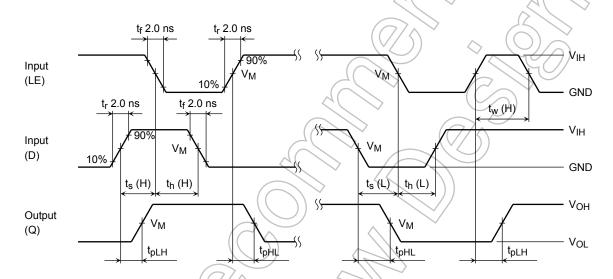


Figure 2 tplH, tpHL, tw, ts, th

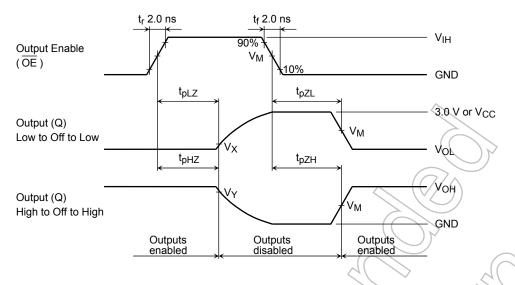
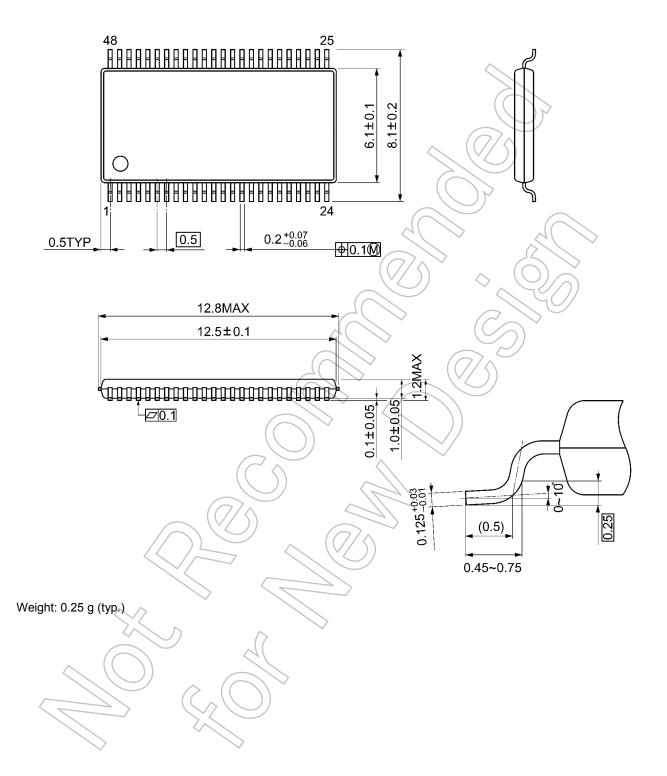


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol	Vce						
Symbol	$3.3\pm0.3~\textrm{V}$	2.5 ± 0.2 V	1.8 V				
V _{IH}	2.7 V	Vcc	v _{cc} (C				
V_{M}	1.5 V	V _{CC} /2	V _{CC} /2				
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V				
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V				

Package Dimensions

TSSOP48-P-0061-0.50A Unit: mm



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